# imall

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## Octal Bidirectional Transceiver with 3-State Inputs/Outputs

The MC74AC245/74ACT245 contains eight non-inverting bidirectional buffers with 3-state outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive  $(T/\overline{R})$  input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a High Z condition.

## Features

- Noninverting Buffers
- Bidirectional Data Path
- A and B Outputs Source/Sink 24 mA
- 'ACT245 has TTL Compatible Inputs
- These are Pb–Free Devices

## **PIN ASSIGNMENT**

| PIN                            | FUNCTION                                 |
|--------------------------------|--|
| ŌĒ                             | Output Enable Input                      |
| T/R                            | Transmit/Receive Input                   |
| A <sub>0</sub> -A <sub>7</sub> | Side A 3–State Inputs or 3–State Outputs |
| B <sub>0</sub> –B <sub>7</sub> | Side B 3–State Inputs or 3–State Outputs |

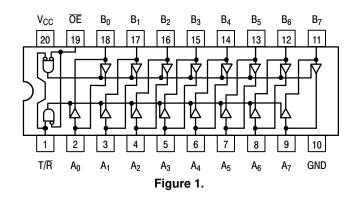
#### **TRUTH TABLES**

| Inp | uts | Quatravita          |  |
|-----|-----|---------------------|--|
| ŌĒ  | T/R | Outputs             |  |
| L   | L   | Bus B Data to Bus A |  |
| L   | Н   | Bus A Data to Bus B |  |
| н   | Х   | High Z State        |  |

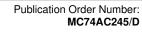
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial









## **ON Semiconductor®**

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SOIC-20W DW SUFFIX CASE 751D



TSSOP-20 DT SUFFIX CASE 948E

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 7 of this data sheet.

## MAXIMUM RATINGS

| Symbol               | Para                                   | meter  | Value                     | Unit |  |
|----------------------|--|--|---------------------------|------|--|
| V <sub>CC</sub>      | DC Supply Voltage (Referenced to GND)  |  | -0.5 to +7.0              | V    |  |
| V <sub>IN</sub>      | DC Input Voltage (Referenced to GND)   | DC Input Voltage (Referenced to GND)   |                           |      |  |
| V <sub>OUT</sub>     | DC Output Voltage (Referenced to GND)  | –0.5 to V <sub>CC</sub> +0.5   | V                         |      |  |
| I <sub>IK</sub>      | DC Input Diode Current                 |  | ±20                       | mA   |  |
| I <sub>OK</sub>      | DC Output Diode Current                |  | ±50                       | mA   |  |
| I <sub>OUT</sub>     | DC Output Sink/Source Current          |  | ±50                       | mA   |  |
| I <sub>CC</sub>      | DC Supply Current, per Output Pin      |  | ±50                       | mA   |  |
| I <sub>GND</sub>     | DC Ground Current, per Output Pin      | ±100   | mA                        |      |  |
| T <sub>STG</sub>     | Storage Temperature Range              | -65 to +150  | °C                        |      |  |
| ΤL                   | Lead temperature, 1 mm from Case for 1 | 0 Seconds  | 260                       | °C   |  |
| TJ                   | Junction Temperature Under Bias        |  | 140                       | °C   |  |
| $\theta_{JA}$        | Thermal Resistance (Note 2)            | SOIC<br>TSSOP  | 65.8<br>110.7             | °C/W |  |
| MSL                  | Moisture Sensitivity                   |  | Level 1                   |      |  |
| F <sub>R</sub>       | Flammability Rating                    | Oxygen Index: 30% – 35%  | UL 94 V–0 @ 0.125 in      |      |  |
| V <sub>ESD</sub>     | ESD Withstand Voltage                  | Human Body Model (Note 3)<br>Machine Model (Note 4)<br>Charged Device Model (Note 5) | > 2000<br>> 200<br>> 1000 | V    |  |
| I <sub>Latchup</sub> | Latchup Performance Abo                | ove $V_{CC}$ and Below GND at 85°C (Note 6)  | ±100                      | mA   |  |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I<sub>OUT</sub> absolute maximum rating must be observed.
 The package thermal impedance is calculated in accordance with JESD 51–7.
 Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22-A115-A.

Tested to JESD22-C101-A. 5.

6. Tested to EIA/JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

| Symbol                             | Parameter  |                         |     | Тур | Max             | Unit  |
|------------------------------------|--|-------------------------|-----|-----|-----------------|-------|
| M                                  | Cumple Vallage   | ′AC                     | 2.0 | 5.0 | 6.0             | V     |
| V <sub>CC</sub>                    | Supply Voltage 'ACT  |                         | 4.5 | 5.0 | 5.5             | V     |
| V <sub>IN</sub> , V <sub>OUT</sub> | DC Input Voltage, Output Voltage (Ref. to GND)                     |                         | 0   | -   | V <sub>CC</sub> | V     |
|                                    |  | V <sub>CC</sub> @ 3.0 V | -   | 150 | -               |       |
| t <sub>r</sub> , t <sub>f</sub>    | out Rise and Fall Time (Note 7)<br>C Devices except Schmitt Inputs | V <sub>CC</sub> @ 4.5 V | -   | 40  | -               | ns/V  |
|                                    |  | V <sub>CC</sub> @ 5.5 V | -   | 25  | -               |       |
|                                    | Input Rise and Fall Time (Note 8)                                  | V <sub>CC</sub> @ 4.5 V | -   | 10  | -               | 100 A |
| t <sub>r</sub> , t <sub>f</sub>    | 'ACT Devices except Schmitt Inputs                                 | V <sub>CC</sub> @ 5.5 V | -   | 8.0 | -               | ns/V  |
| T <sub>A</sub>                     | Operating Ambient Temperature Range                                |                         | -40 | 25  | 85              | °C    |
| I <sub>OH</sub>                    | Output Current – High  |                         | -   | -   | -24             | mA    |
| I <sub>OL</sub>                    | Output Current – Low   |                         |     | _   | 24              | mA    |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
7. V<sub>IN</sub> from 30% to 70% V<sub>CC</sub>; see individual Data Sheets for devices that differ from the typical input rise and fall times.
8. V<sub>IN</sub> from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

## **DC CHARACTERISTICS**

|                  | Parameter                            |                        | 74AC                    |                      | 74AC                                  |      |   |
|------------------|--------------------------------------|------------------------|-------------------------|----------------------|---------------------------------------|------|---|
| Symbol           |                                      | V <sub>CC</sub><br>(V) | T <sub>A</sub> = +25°C  |                      | T <sub>A</sub> =<br>-40°C to<br>+85°C | Unit | Conditions  |
|                  |                                      |                        | Тур                     | Guar                 | anteed Limits                         |      |   |
| V <sub>IH</sub>  | Minimum High Level<br>Input Voltage  | 3.0<br>4.5<br>5.5      | 1.5<br>2.25<br>2.75     | 2.1<br>3.15<br>3.85  | 2.1<br>3.15<br>3.85                   | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$  |
| V <sub>IL</sub>  | Maximum Low Level<br>Input Voltage   | 3.0<br>4.5<br>5.5      | 1.5<br>2.25<br>2.75     | 0.9<br>1.35<br>1.65  | 0.9<br>1.35<br>1.65                   | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$  |
| V <sub>OH</sub>  | Minimum High Level<br>Output Voltage | 3.0<br>4.5<br>5.5      | 2.99<br>4.49<br>5.49    | 2.9<br>4.4<br>5.4    | 2.9<br>4.4<br>5.4                     | V    | I <sub>OUT</sub> = -50 μA   |
|                  |                                      | 3.0<br>4.5<br>5.5      |                         | 2.56<br>3.86<br>4.86 | 2.46<br>3.76<br>4.76                  | v    | $\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ -12 \text{ mA} \\ I_{OH} -24 \text{ mA} \\ -24 \text{ mA} \end{array}$     |
| V <sub>OL</sub>  | Maximum Low Level<br>Output Voltage  | 3.0<br>4.5<br>5.5      | 0.002<br>0.001<br>0.001 | 0.1<br>0.1<br>0.1    | 0.1<br>0.1<br>0.1                     | V    | I <sub>OUT</sub> = 50 μA  |
|                  |                                      | 3.0<br>4.5<br>5.5      |                         | 0.36<br>0.36<br>0.36 | 0.44<br>0.44<br>0.44                  | V    | $\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ 12 \text{ mA} \\ I_{OL} \qquad 24 \text{ mA} \\ 24 \text{ mA} \end{array}$ |
| I <sub>IN</sub>  | Maximum Input<br>Leakage Current     | 5.5                    | -                       | ±0.1                 | ±1.0                                  | μΑ   | $V_{I} = V_{CC}, GND$   |
| I <sub>OZT</sub> | Maximum<br>3-State<br>Current        | 5.5                    | -                       | ±0.6                 | ±6.0                                  | μΑ   | $V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$   |
| I <sub>OLD</sub> | †Minimum Dynamic                     | 5.5                    | -                       | -                    | 75                                    | mA   | $V_{OLD} = 1.65 \text{ V Max}$  |
| I <sub>OHD</sub> | Output Current                       | 5.5                    | -                       | -                    | -75                                   | mA   | V <sub>OHD</sub> = 3.85 V Min   |
| I <sub>CC</sub>  | Maximum Quiescent<br>Supply Current  | 5.5                    | -                       | 8.0                  | 80.0                                  | μA   | $V_{IN} = V_{CC}$ or GND  |

\*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time. NOTE:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

## AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

|                  |   |                          |            | 74AC                  |             | 74         | AC                     |      |             |
|------------------|---|--------------------------|------------|-----------------------|-------------|------------|------------------------|------|-------------|
| Symbol           | Parameter   | V <sub>CC</sub> *<br>(V) |            | ₄ = +25°<br>cL = 50 p |             |            | -40°C<br>85°C<br>50 pF | Unit | Fig.<br>No. |
|                  |   |                          | Min        | Тур                   | Max         | Min        | Max                    |      |             |
| t <sub>PLH</sub> | Propagation Delay<br>A <sub>n</sub> to B <sub>n</sub> or B <sub>n</sub> to A <sub>n</sub> | 3.3<br>5.0               | 1.5<br>1.5 | 5.0<br>3.5            | 8.5<br>6.5  | 1.0<br>1.0 | 9.0<br>7.0             | ns   | 3–5         |
| t <sub>PHL</sub> | Propagation Delay<br>A <sub>n</sub> to B <sub>n</sub> or B <sub>n</sub> to A <sub>n</sub> | 3.3<br>5.0               | 1.5<br>1.5 | 5.0<br>3.5            | 8.5<br>6.0  | 1.0<br>1.0 | 9.0<br>7.0             | ns   | 3–5         |
| t <sub>PZH</sub> | Output Enable Time  | 3.3<br>5.0               | 2.5<br>1.5 | 7.0<br>5.0            | 11.5<br>8.5 | 2.0<br>1.0 | 12.5<br>9.0            | ns   | 3–7         |
| t <sub>PZL</sub> | Output Enable Time  | 3.3<br>5.0               | 2.5<br>1.5 | 7.5<br>5.5            | 12.0<br>9.0 | 2.0<br>1.0 | 13.5<br>9.5            | ns   | 3–8         |
| t <sub>PHZ</sub> | Output Disable Time   | 3.3<br>5.0               | 2.0<br>1.5 | 6.5<br>5.5            | 12.0<br>9.0 | 1.0<br>1.0 | 12.5<br>10.0           | ns   | 3–7         |
| t <sub>PLZ</sub> | Output Disable Time   | 3.3<br>5.0               | 2.0<br>1.5 | 7.0<br>5.5            | 11.5<br>9.0 | 1.5<br>1.0 | 13.0<br>10.0           | ns   | 3–8         |

\*Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

## **DC CHARACTERISTICS**

|                  | Parameter                              |                        | 744                    | СТ           | 74ACT                                |      |  |
|------------------|--|------------------------|------------------------|--------------|--------------------------------------|------|--|
| Symbol           |  | V <sub>CC</sub><br>(V) | T <sub>A</sub> = +25°C |              | T <sub>A</sub> =<br>40°C to<br>+85°C | Unit | Conditions   |
|                  |  |                        | Тур                    | Guar         | anteed Limits                        |      |  |
| V <sub>IH</sub>  | Minimum High Level<br>Input Voltage    | 4.5<br>5.5             | 1.5<br>1.5             | 2.0<br>2.0   | 2.0<br>2.0                           | v    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$   |
| V <sub>IL</sub>  | Maximum Low Level<br>Input Voltage     | 4.5<br>5.5             | 1.5<br>1.5             | 0.8<br>0.8   | 0.8<br>0.8                           | v    | $\label{eq:VOUT} \begin{array}{l} V_{OUT} = 0.1 \ V \\ \text{or} \ V_{CC} - 0.1 \ V \end{array}$ |
| V <sub>OH</sub>  | Minimum High Level<br>Output Voltage   | 4.5<br>5.5             | 4.49<br>5.49           | 4.4<br>5.4   | 4.4<br>5.4                           | v    | I <sub>OUT</sub> = -50 μA  |
|                  |  | 4.5<br>5.5             |                        | 3.86<br>4.86 | 3.76<br>4.76                         | v    | $V_{IN} = V_{IL} \text{ or } V_{IH}$<br>$I_{OH} -24 \text{ mA}$<br>-24  mA                       |
| V <sub>OL</sub>  | Maximum Low Level<br>Output Voltage    | 4.5<br>5.5             | 0.001<br>0.001         | 0.1<br>0.1   | 0.1<br>0.1                           | v    | l <sub>OUT</sub> = 50 μA   |
|                  |  | 4.5<br>5.5             |                        | 0.36<br>0.36 | 0.44<br>0.44                         | v    | $V_{IN} = V_{IL} \text{ or } V_{IH}$<br>24 mA<br>$I_{OL}$ 24 mA                                  |
| I <sub>IN</sub>  | Maximum Input<br>Leakage Current       | 5.5                    | -                      | ±0.1         | ±1.0                                 | μΑ   | $V_{I} = V_{CC}, \text{ GND}$  |
| $\Delta I_{CCT}$ | Additional Max. I <sub>CC</sub> /Input | 5.5                    | 0.6                    | -            | 1.5                                  | mA   | $V_{I} = V_{CC} - 2.1 V$   |
| I <sub>OZT</sub> | Maximum<br>3-State<br>Current          | 5.5                    | _                      | ±0.6         | ±6.0                                 | μΑ   |  |
| I <sub>OLD</sub> | †Minimum Dynamic                       | 5.5                    | -                      | -            | 75                                   | mA   | V <sub>OLD</sub> = 1.65 V Max  |
| I <sub>OHD</sub> | Output Current                         | 5.5                    | -                      | -            | -75                                  | mA   | V <sub>OHD</sub> = 3.85 V Min  |
| I <sub>CC</sub>  | Maximum Quiescent<br>Supply Current    | 5.5                    | -                      | 8.0          | 80.0                                 | μΑ   | $V_{IN} = V_{CC}$ or GND   |

\*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

#### 74ACT 74ACT $T_A = -40^{\circ}C$ T<sub>A</sub> = +25°C V<sub>CC</sub>\* Fig. Symbol Parameter to +85°C Unit $C_L = 50 \text{ pF}$ (V) No. $C_L = 50 \text{ pF}$ Min Тур Мах Min Max Propagation Delay, $A_n$ to $B_n$ or $B_n$ to $A_n$ 5.0 1.5 4.0 7.5 1.5 8.0 ns 3–5 t<sub>PLH</sub> t<sub>PHL</sub> Propagation Delay, An to Bn or Bn to An 5.0 1.5 4.0 8.0 1.0 9.0 ns 3–5 Output Enable Time 5.0 1.5 5.0 10 1.5 11.0 ns 3–7 t<sub>PZH</sub> **Output Enable Time** 5.0 1.5 5.5 10 1.5 12.0 ns 3–8 t<sub>PZL</sub> **Output Disable Time** 5.0 1.5 5.5 10 1.0 3–7 t<sub>PHZ</sub> 11.0 ns 2.0 5.0 5.0 10 1.5 11.0 3–8 t<sub>PLZ</sub> **Output Disable Time** ns

### AC CHARACTERISTICS (For Figures and Waveforms – See AND8277/D at www.onsemi.com)

\*Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

## CAPACITANCE

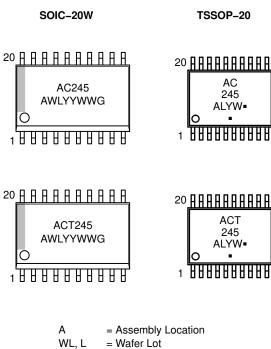
| Symbol           | Parameter                     | Value<br>Typ | Unit | Test Conditions         |
|------------------|-------------------------------|--------------|------|-------------------------|
| C <sub>IN</sub>  | Input Capacitance             | 4.5          | pF   | V <sub>CC</sub> = 5.0 V |
| C <sub>I/O</sub> | Input/Output Capacitance      | 15           | pF   | V <sub>CC</sub> = 5.0 V |
| C <sub>PD</sub>  | Power Dissipation Capacitance | 45           | pF   | V <sub>CC</sub> = 5.0 V |

## **ORDERING INFORMATION**

| Device          | Package               | Shipping <sup>†</sup> |
|-----------------|-----------------------|-----------------------|
| MC74AC245DWG    | SOIC-20<br>(Pb-Free)  | 38 Units / Rail       |
| MC74AC245DWR2G  | SOIC-20<br>(Pb-Free)  | 1000 / Tape & Reel    |
| MC74ACT245DWG   | SOIC-20<br>(Pb-Free)  | 38 Units / Rail       |
| MC74ACT245DWR2G | SOIC-20<br>(Pb-Free)  | 1000 / Tape & Reel    |
| MC74AC245DTG    | TSSOP–20<br>(Pb–Free) | 75 Units / Rail       |
| MC74AC245DTR2G  | TSSOP-20<br>(Pb-Free) | 2500 / Tape & Reel    |
| MC74ACT245DTG   | TSSOP-20<br>(Pb-Free) | 75 Units / Rail       |
| MC74ACT245DTR2G | TSSOP-20<br>(Pb-Free) | 2500 / Tape & Reel    |

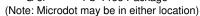
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MARKING DIAGRAMS

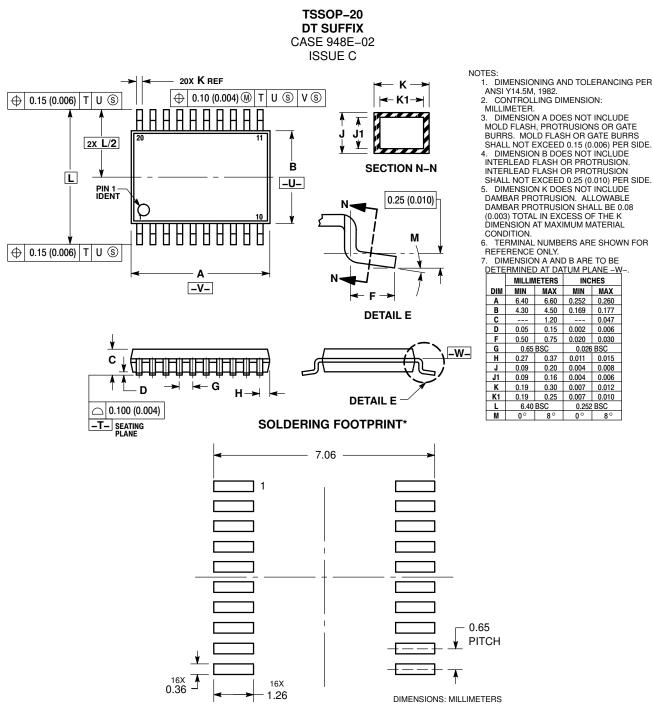


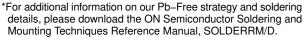
| VVL, L | = water Lo |
|--------|------------|
| YY, Y  | = Year     |

- WW, W = Work Week
- G or = Pb–Free Package



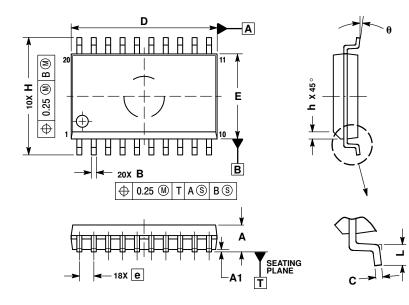
## PACKAGE DIMENSIONS





## PACKAGE DIMENSIONS

SOIC-20W **DW SUFFIX** CASE 751D-05 **ISSUE G** 



NOTES

DIMENSIONS ARE IN MILLIMETERS 1. 2.

- INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994. 3
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. DIMENSION B DOES NOT INCLUDE DAMBAR 5 PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIMETERS |       |  |  |  |
|-----|-------------|-------|--|--|--|
| DIM | MIN         | MAX   |  |  |  |
| Α   | 2.35        | 2.65  |  |  |  |
| A1  | 0.10        | 0.25  |  |  |  |
| В   | 0.35        | 0.49  |  |  |  |
| С   | 0.23        | 0.32  |  |  |  |
| D   | 12.65       | 12.95 |  |  |  |
| Е   | 7.40        | 7.60  |  |  |  |
| е   | 1.27        | BSC   |  |  |  |
| Н   | 10.05       | 10.55 |  |  |  |
| h   | 0.25        | 0.75  |  |  |  |
| L   | 0.50        | 0.90  |  |  |  |
| θ   | 0 °         | 7 °   |  |  |  |
|     |             |       |  |  |  |

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